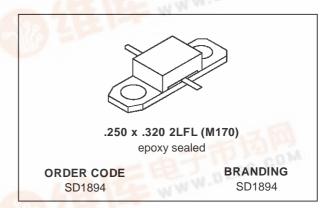


SD1894

RF & MICROWAVE TRANSISTORS SATELLITE COMMUNICATIONS APPLICATIONS

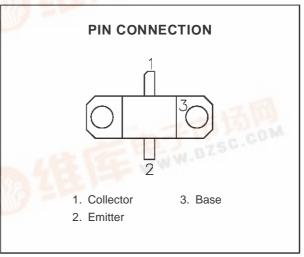
- CLASS C
- 1.6 GHz
- COMMON BASE
- REFRACTORY/GOLD METALLIZATION
- EFFICIENCY = 50% MIN.
- P_{OUT} = 4.5 W MIN. WITH 10 dB GAIN



DESCRIPTION

The SD1894 is a common base silicon NPN bipolar device optimized for 1.6 GHz SATCOM applications.

The SD1894 offers superior gain and collector efficiency, making it an ideal choice for Class C power amplifiers used in portable as well as fixed SAT-COM terminals.



ABSOLUTE MAXIMUM RATINGS $(T_{case} = 25^{\circ}C)$

Symbol	Parameter	Value	Unit
Vсво	Collector-Base Voltage	45	DISCV
Vces	Collector-Emitter Voltage	45	V
VEBO	Emitter-Base Voltage	3.0	V
Ic	Device Current	375	mA
P _{DISS}	Power Dissipation	12.5	W
TJ	Junction Temperature	+200	°C
T _{STG}	Storage Temperature	- 65 to +150	°C

THERMAL DATA

技	PRIH(j-c)	Junction-Case Thermal Resistance	14.0	°C/W	
	IN CO.				

February 4, 1997

SD1894

ELECTRICAL SPECIFICATIONS (T_{case} = 25°C)

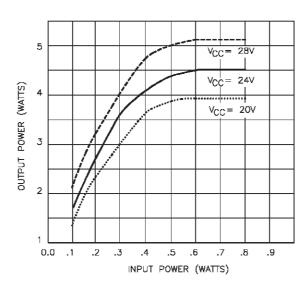
STATIC

Symbol	Test Conditions	Value			Unit	
	rest conditions		Min.	Тур.	Max.	Ollit
ВУсво	$I_C = 1 \text{ mA}$ $I_E =$	0 mA	45	_	_	V
BV _{CES}	$I_C = 1 \text{ mA}$ V_{BE}	= 0 V	45	_	_	V
BV _{EBO}	$I_E = 1 \text{ mA}$ $I_C =$	0 mA	3.0	_	_	V
I _{CBO}	V _{CB} = 28 V I _E =	0 mA	_	_	.25	mA
h _{FE}	V _{CE} = 5 V I _C =	.2 A	15	_	150	

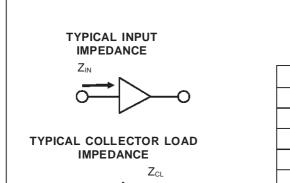
DYNAMIC

Symbol	Test Conditions			Value			Unit
Symbol				Min.	Тур.	Max.	Oilit
P _{IN}	f = 1650 MHz	$V_{CC} = 28 \text{ V}$	$P_{OUT} = 4.5 W$.35	.45	W
ης	f = 1650 MHz	$V_{CC} = 28 \text{ V}$	$P_{OUT} = 4.5 W$	50	55	_	%
P _G	f = 1650 MHz	V _{CC} = 28 V	P _{OUT} = 4.5 W	10.0	11.1	_	dB
Load Mismatch	V _{CC} = 28 V	P _{OUT} = 4.5 W	VSWR = 20:1	1	_	adation ir Power	1

INPUT POWER vs OUTPUT POWER

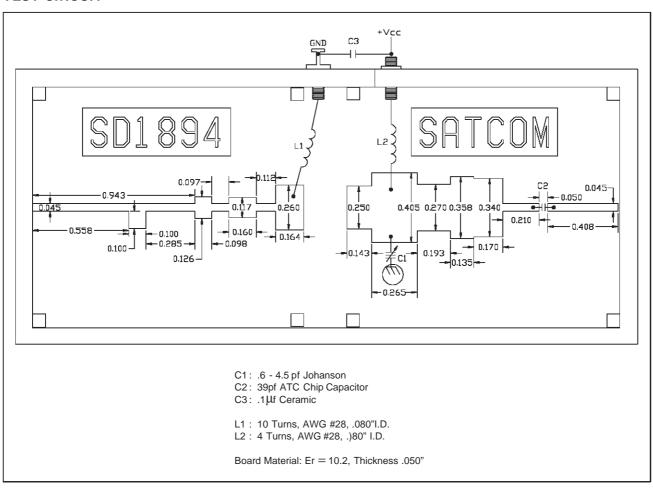


IMPEDANCE DATA



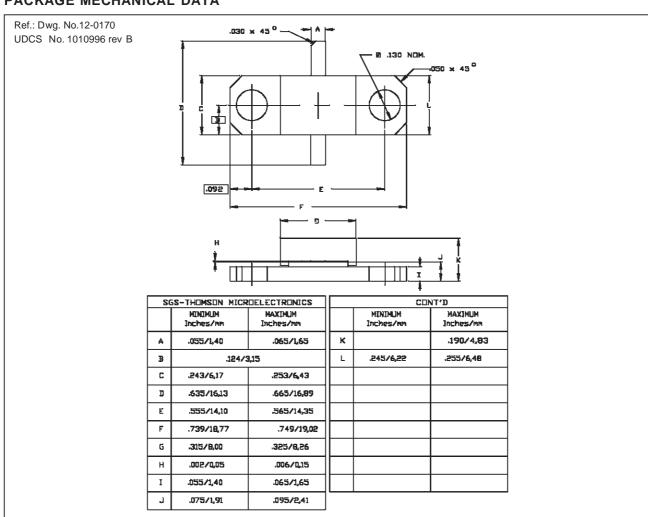
FREQ.	Z _{IN} (Ω)	Z _{CL} (Ω)
1600 MHz	31.6 + j 21.4	5.2 + j 14.7
1620 MHz	38.0 + j 15.0	5.6 + j 14.55
1635 MHz	38.8 + j 11.3	5.85 + j 14.45
1650 MHz	36.0 + j 9.1	6.1 + j 14.3
1665 MHz	34.3 + j 8.77	6.37 + j 14.2

TEST CIRCUIT



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PACKAGE MECHANICAL DATA



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